

LP50xx 9-, 12-Channel, 12-Bit PWM Ultra-low Quiescent Current I²C RGB LED Drivers

1 Features

- · Operating voltage range:
 - V_{CC} range: 2.7 V to 5.5 V
 - EN, SDA, and SCL pins compatible with 1.8-V, 3.3-V, and 5-V power rails
 - Output maximum voltage: 6 V
- 12 Constant-current sinks with high precision
 - 25.5 mA Maximum per channel with V_{CC} in full
 - 35 mA Maximum per channel when V_{CC} ≥ 3.3 V
 - Device-to-device error: ±5%; channel-tochannel error: ±5%
- Ultra-low quiescent current:
 - Shutdown mode: 1 µA (maximum) with EN low
 - Power-saving mode: 10 μA (typical) with EN high and all LEDs off for > 30 ms
- Integrated 12-bit, 29-kHz PWM generator for each channel:
 - Independent color-mixing register per channel
 - Independent brightness-control register per **RGB LED module**
 - Optional logarithmic- or linear-scale brightness
 - Integrated 3-phase PWM-shifting scheme
- 3 Programmable banks (R, G, B) for easy software control of each color
- 2 External hardware address pins allow connecting up to 4 devices
- Broadcast slave address allows configuring multiple devices simultaneously
- Auto-increment allows writing or reading consecutive registers within one transmission
- Up to 400-kHz fast-mode I²C speed

2 Applications

LED lighting, indicator lights, and fun lights for:

- Smart speaker (with voice assistant)
- Smart home appliances
- Video doorbell
- Electronic smart lock
- Smoke and heat detector
- STB and DVR
- Smart router
- Handheld device

3 Description

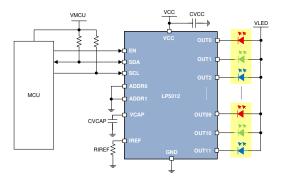
In smart homes and other applications that use human-machine-interaction, high-performance RGB LED drivers are required. LED animation effects such as flashing, breathing and chasing that greatly improves user experience, and minimal system noise is essential.

The LP50xx device is an 9- or 12-channel constant current sink LED driver. The LP50xx device includes integrated color mixing and brightness control, and pre-configuration simplifies the software coding process. Integrated 12-bit, 29-kHz PWM generators for each channel enable smooth, vivid color for LEDs, and eliminate audible noise.

Device Information

PART NUMBER(1)	PACKAGE	BODY SIZE (NOM)		
LP5009	WQFN (20)	3.00 mm × 3.00 mm		
LP5012	WQFN (20)	3.00 11111 ^ 3.00 11111		
LP5009	TSSOD (24)	7.80 mm × 4.40 mm		
LP5012	TSSOP (24)	7.00 111111 × 4.40 111111		

For all available packages, see the orderable addendum at the end of the data sheet.



Simplified Schematic



Table of Contents

1 Features	1	8.5 Programming	. 19
2 Applications		8.6 Register Maps	
3 Description		9 Application and Implementation	
4 Revision History		9.1 Application Information	
5 Description (continued)		9.2 Typical Application	
6 Pin Configuration and Functions	4	10 Power Supply Recommendations	
7 Specifications		11 Layout	
7.1 Absolute Maximum Ratings		11.1 Layout Guidelines	
7.2 ESD Ratings	7	11.2 Layout Examples	
7.3 Recommended Operating Conditions		12 Device and Documentation Support	40
7.4 Thermal Information		12.1 Related Links	40
7.5 Electrical Characteristics	8	12.2 Receiving Notification of Documentation Updates	
7.6 Timing Characteristics	9	12.3 Support Resources	
7.7 Typical Characteristics		12.4 Trademarks	
8 Detailed Description		12.5 Electrostatic Discharge Caution	
8.1 Overview		12.6 Glossary	
8.2 Functional Block Diagram		13 Mechanical, Packaging, and Orderable	
8.3 Feature Description		Information	. 40
8.4 Device Functional Modes			

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision A (July 2019) to Revision B (August 2020)	Page
•	Updated the numbering format for tables, figures and cross-references throughout the document	1
•	Added PW package option to data sheet	1
С	hanges from Revision * (May 2019) to Revision A (July 2019)	Page
•	Changed from Advance Information to Production Data	1



5 Description (continued)

The LP50xx device controls each LED output with a 12-bit PWM resolution at 29-kHz switching frequency, which helps achieve a smooth dimming effect and eliminates audible noise. The independent color mixing and intensity control registers make the software coding straightforward. When targeting a fade-in, fade-out type breathing effect, the global R, G, B bank control reduces the microcontroller loading significantly. The LP50xx device also implements a PWM phase-shifting function to help reduce the input power budget when LEDs turn on simultaneously.

The LP50xx device implements an automatic power-saving mode to achieve ultra-low quiescent current. When channels are all off for 30 ms, the device total power consumption is down to 10 μ A, which makes the LP50xx device a potential choice for battery-powered end equipment.



6 Pin Configuration and Functions

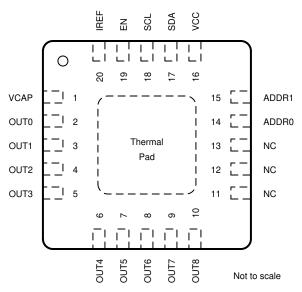


Figure 6-1. LP5009 RUK Package 20-Pin WQFN With Exposed Thermal Pad Top View

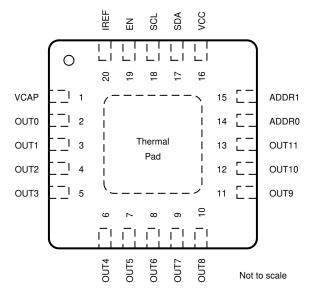


Figure 6-2. LP5012 RUK Package 20-Pin WQFN With Exposed Thermal Pad Top View



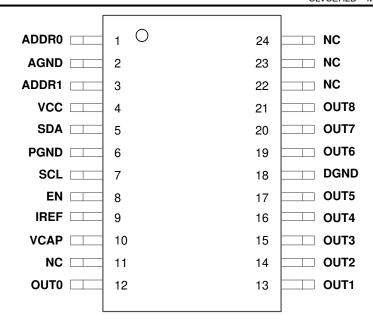


Figure 6-3. LP5009 PW Package 24-Pin TSSOP Top View

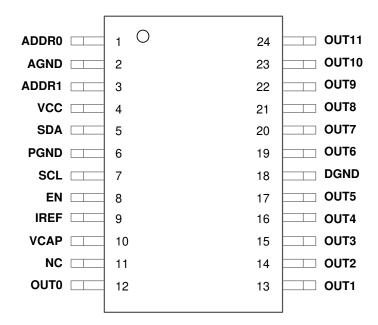


Figure 6-4. LP5012 PW Package 24-Pin TSSOP Top View



Pin Functions

PIN						
NAME	RUK	NO.	PW	NO.	I/O	DESCRIPTION
NAIVIE	LP5009	LP5012	LP5009	LP5012		
ADDR0	14	14	1	1	_	I ² C slave-address selection pin. This pin must not be left floating.
ADDR1	15	15	3	3	_	I ² C slave-address selection pin. This pin must not be left floating.
EN	19	19	8	8	ı	Chip enable input pin.
IREF	20	20	9	9	_	Output current-reference global-setting pin.
NC	11, 12, 13	_	22, 23, 24	_	_	No internal connection.
OUT0	2	2	12	12	0	Current sink output 0. If not used, this pin can be left floating.
OUT1	3	3	13	13	0	Current sink output 1. If not used, this pin can be left floating.
OUT2	4	4	14	14	0	Current sink output 2. If not used, this pin can be left floating.
OUT3	5	5	15	15	0	Current sink output 3. If not used, this pin can be left floating.
OUT4	6	6	16	16	0	Current sink output 4. If not used, this pin can be left floating.
OUT5	7	7	17	17	0	Current sink output 5. If not used, this pin can be left floating.
OUT6	8	8	19	19	0	Current sink output 6. If not used, this pin can be left floating.
OUT7	9	9	20	20	0	Current sink output 7. If not used, this pin can be left floating.
OUT8	10	10	21	21	0	Current sink output 8. If not used, this pin can be left floating.
OUT9	_	11	_	22	0	Current sink output 9. If not used, this pin can be left floating.
OUT10	_	12	_	23	0	Current sink output 10. If not used, this pin can be left floating.
OUT11	_	13	_	24	0	Current sink output 11. If not used, this pin can be left floating.
SCL	18	18	7	7	I	$\rm I^2C$ bus clock line. If not used, this pin must be connected to GND or VCC.
SDA	17	17	5	5	I/O	I ² C bus data line. If not used, this pin must be connected to GND or VCC.
VCAP	1	1	10	10	_	Internal LDO output pin, this pin must be connected to a 1-µF capacitor to GND. Place the capacitor as close to the device as possible.
vcc	16	16	4	4	_	Power supply.
GND	Thermal pad	Thermal pad	_	_	_	Exposed thermal pad also serves the ground pin for the WQFN package.
AGND	_	_	2	2	_	Analog circuits ground. AGND, PGND and DGND must be conntected together.
PGND	_	_	6	6	_	Power ground. AGND, PGND and DGND must be conntected together.
DGND	_	_	18	18	_	Digital circuits ground. AGND, PGND and DGND must be conntected together.



7 Specifications

7.1 Absolute Maximum Ratings

over operating ambient temperature range (unless otherwise noted)(1)

	MIN	MAX	UNIT
Voltage on EN, IREF, OUTx, SCL, SDA, VCC	-0.3	6	V
Voltage on ADDRx	-0.3	VCC + 0.3	V
Voltage on VCAP	-0.3	2	V
Continuous power dissipation	Internally	limited	
Junction temperature, T _{J-MAX}	-40	125	°C
Storage temperature, T _{stg}	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
V _(ESD) Electrostatic discharge		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±4000	.,
V _(ESD)		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1500]

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions.

7.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

1 3 1	,		
	MIN	MAX	UNIT
Input voltage on VCC	2.7	5.5	V
Voltage on OUTx	0	5.5	V
Voltage on ADDRx, EN, SDA, SCL	0	5.5	V
Operating ambient temperature, T _A	-40	85	°C

7.4 Thermal Information

			LP5009 or LP5012		
	THERMAL METRIC(1)	RUK (QFN)	PW (TSSOP)	UNIT	
		20 PINS	24 Pins		
R _{θJA}	Junction-to-ambient thermal resistance	53.7	98.3	°C/W	
R _{θJC(top)}	Junction-to-case (top) thermal resistance	55.3	41.5	°C/W	
R _{θJB}	Junction-to-board thermal resistance	27.4	53.5	°C/W	
ΨЈТ	Junction-to-top characterization parameter	1.9	5.0	°C/W	
ΨЈВ	Junction-to-board characterization parameter	27.4	53.1	°C/W	
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	12.9	n/a	°C/W	

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions.



7.5 Electrical Characteristics

over operating ambient temperature range (-40° C < T_A< 85° C) (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER S	UPPLIES (VCC)					
V _{VCC}	Supply voltage		2.7		5.5	V
	Shutdown supply current	V _{EN} = 0 V		0.2	1	
	Standby supply current	V _{EN} = 3.3 V, Chip_EN = 0 (bit)		6	10	μA
VCC	Normal-mode supply current	With 10-mA LED current per OUTx		4	6	mA
	Power-save mode supply current	V _{EN} = 3.3 V, Chip_EN = 1 (bit), Power_Save_EN = 1 (bit), all the LEDs off duration > t _{PSM}		6	10	μΑ
V _{UVR}	Undervoltage restart	V _{VCC} rising			2.5	V
V _{UVF}	Undervoltage shutdown	V _{VCC} falling	2			V
V _{UV_HYS}	Undervoltage shutdown hysteresis			0.2		V
OUTPUT S	STAGE (OUTx)				•	
	Maximum sink current (OUT0-OUTx) (For LP5012, x = 11. For LP5009, x = 8.)	V _{VCC} in full range, Max_Current_Option = 0 (bit), PWM = 100%			25.5	mA
I _{MAX}	Maximum sink current (OUT0-OUTx) (For LP5012, x = 11. For LP5009, x = 8.)	V _{VCC} ≥ 3.3 V, Max_Current_Option = 1 (bit), PWM = 100%			35	MA
_	Internal sink current limit (OUT0-OUTx) (For LP5012, x = 11. For LP5009, x = 8.)	V _{VCC} in full range, Max_Current_Option = 0 (bit), V _{IREF} = 0 V	35	55	85	mA
I _{LIM}	Internal sink current limit (OUT0-OUTx) (For LP5012, x = 11. For LP5009, x = 8.)	V _{VCC} ≥ 3.3V, Max_Current_Option=1 (bit), V _{IREF} = 0 V	40	75	120	
I _{lkg}	Leakage current (OUT0-OUTx) (For LP5012, x = 11. For LP5009, x = 8.)	PWM = 0%		0.1	1	μA
I _{ERR_DD}	Device to device current error, I _{ERR_DD} = (I _{AVE} - I _{SET})/I _{SET} × 100%	Channels' current are set to 10 mA. PWM = 100% at 25°C. Already includes the V _{IREF} and K _{IREF} tolerance	-5%		5%	
I _{ERR_CC}	Channel to channel current error, I _{ERR_CC} = (I _{OUTX} - I _{AVE})/I _{AVE} × 100%	Channels' current are set to 10 mA. PWM = 100% at 25°C. Already includes the V _{IREF} and K _{IREF} tolerance	-5%		5%	
V _{IREF}	IREF voltage			0.7		V
K _{IREF}	IREF ratio			105		
f_{PWM}	PWM switching frequency		21	29		kHz
.,	Output paturation valtage	V _{VCC} in full range, Max_Current_Option = 0 (bit), output current set to 20 mA, the voltage when the LED current has dropped 5%		0.25	0.35	V
V _{SAT}	Output saturation voltage	V _{VCC} ≥ 3.3 V, Max_Current_Option = 1 (bit), output current set to 20 mA, the voltage when the LED current has dropped 5%		0.3	0.4	V

Product Folder Links: LP5009 LP5012

7.5 Electrical Characteristics (continued)

over operating ambient temperature range (-40° C < T_A < 85° C) (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP MA	X UNIT	
LOGIC IN	OGIC INPUTS (EN, SCL, SDA, ADDRx)					
V _{IL}	Low level input voltage			0	4 V	
V _{IH}	High level input voltage		1.4		V	
I _{LOGIC}	Input current		-1		1 µA	
V _{SDA}	SDA output low level	I _{PULLUP} = 5 mA		0	4 V	
PROTECT	PROTECTION CIRCUITS					
T _(TSD)	Thermal-shutdown junction temperature			160	°C	
T _(HYS)	Thermal shutdown temperature hysteresis			15	°C	

7.6 Timing Characteristics

over operating ambient temperature range (- 40° C < T_A < 85° C) (unless otherwise noted)

·	PARAMETER	MIN	TYP	MAX	UNIT
fosc	Internal oscillator frequency		15		MHz
t _{PSM}	Power save mode deglitch time	20	30	40	ms
t _{EN_H}	EN first rising edge until first I ² C access			500	μs
t _{EN_L}	EN first falling edge until first I ² C reset			3	μs
f_{SCL}	I ² C clock frequency			400	kHz
1	Hold time (repeated) START condition	0.6			μs
2	Clock low time	1.3			μs
3	Clock high time	600			ns
4	Setup time for a repeated START condition	600			ns
5	Data hold time	0			ns
6	Data setup time	100			ns
7	Rise time of SDA and SCL	20 + 0.1 C _b		300	ns
8	Fall time of SDA and SCL	15 + 0.1 C _b		300	ns
9	Setup time for STOP condition	600			ns
10	Bus free time between a STOP and a START condition	1.3			μs
C _b	Capacitive load parameter for each bus line Load of 1 pF corresponds to one nanosecond.	10		200	pF

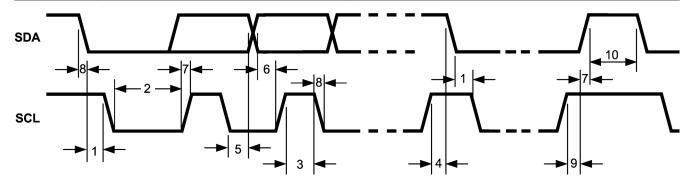
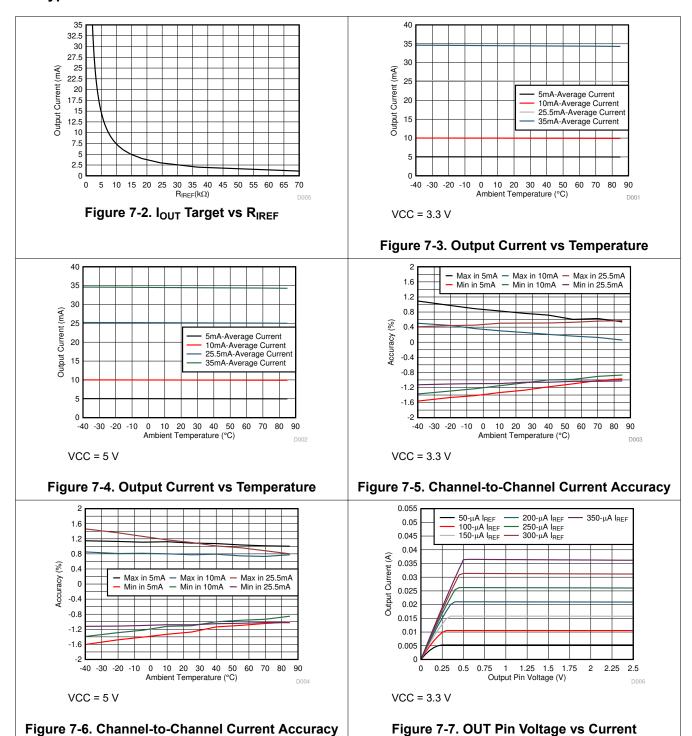


Figure 7-1. I²C Timing Parameters

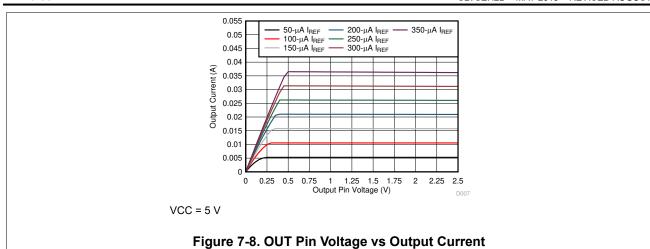


7.7 Typical Characteristics



vs Temperature





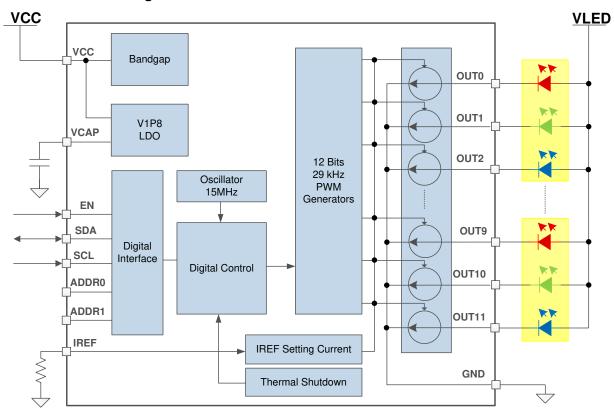
8 Detailed Description

8.1 Overview

The LP50xx device is an 9- or 12-channel constant-current-sink LED driver. The LP50xx device includes all necessary power rails, an on-chip oscillator, and a two-wire serial I^2C interface. The maximum constant-current value of all channels is set by a single external resistor. Two hardware address pins allow up to four devices on the same bus. An automatic power-saving mode is implemented to keep the total current consumption under 10 μ A, which makes the LP50xx device a potential choice for battery-powered end equipment.

The LP50xx device is optimized for RGB LEDs regarding both live effects and software efforts. The LP50xx device controls each LED output with 12-bit PWM resolution at 29-kHz switching frequency, which helps achieve a smooth dimming effect and eliminates audible noise. The independent color-mixing and intensity-control registers make the software coding straightforward. When targeting a fade-in, fade-out type breathing effect, the global RGB bank control reduces the microcontroller loading significantly. The LP50xx device also implements a PWM phase-shifting function to help reduce the input power budget when LEDs turn on simultaneously.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 PWM Control for Each Channel

Most traditional LED drivers are designed for the single-color LEDs, in which the high-resolution PWM generator is used for intensity control only. However, for RGB LEDs, both the color mixing and intensity control must be addressed to achieve the target effect. With the traditional solution, the users must handle the color mixing and intensity control simultaneously with a single PWM register. Several undesired effects occur: the limited dimming steps, the complex software design and the color distortion when using a logarithmic scale control.

The LP50xx device is designed with independent color mixing and intensity control, which makes the RGB LED effects fancy and the control experience straightforward. With the inputs of the color-mixing register and the intensity-control register, the final PWM generator output for each channel is 12-bit resolution and 29-kHz dimming frequency, which helps achieve a smooth dimming effect and eliminates audible noise. See Figure 8-1.

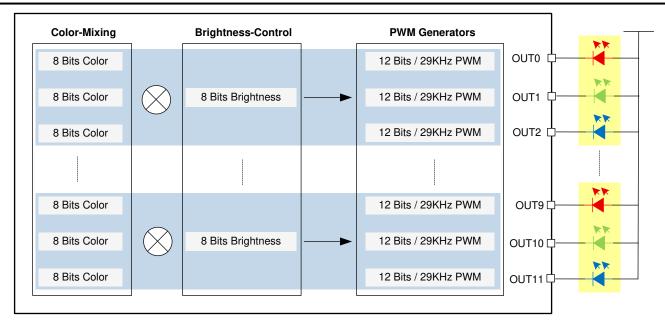


Figure 8-1. PWM Control Scheme for Each Channel

8.3.1.1 Independent Color Mixing Per RGB LED Module

Each output channel has its own individual 8-bit color-setting register (OUTx_COLOR). The device allows every RGB LED module to achieve >16 million (256 × 256 × 256) color-mixing.

8.3.1.2 Independent Intensity Control Per RGB LED Module

When color is fixed, the independent intensity-control is used to achieve accurate and flexible dimming control for every RGB LED module.

8.3.1.2.1 Intensity-Control Register Configuration

Every three consecutive output channels are assigned to their respective intensity-control register (LEDx_BRIGHTNESS). For example, OUT0, OUT1, and OUT2 are assigned to LED0_BRIGHTNESS, so it is recommended to connect the RGB LEDs in the sequence as shown in Table 8-1. The LP50xx device allows 256-step intensity control for each RGB LED module, which helps achieve a smooth dimming effect.

Keeping FFh (default value) in the LED0_BRIGHTNESS register results in 100% dimming duty cycle. With this setting, users can just configure the color mixing register by channel to achieve the target dimming effect in a single-color LED application.

8.3.1.2.2 Logarithmic- or Linear-Scale Intensity Control

For human-eye-friendly visual performance, a logarithmic-scale dimming curve is usually implemented in LED drivers. However, for RGB LEDs, if using a single register to achieve both color mixing and intensity control, color distortion can be observed easily when using a logarithmic scale. The LP50xx device, with independent color-mixing and intensity-control registers, implements the logarithmic scale dimming control inside the intensity control function, which solves the color distortion issue effectively. See Figure 8-2. Also, the LP50xx device allows users to configure the dimming scale either logarithmically or linearly through the global Log_Scale_EN register. If a special dimming curve is desired, using the linear scale with software correction is the most flexible approach. See Figure 8-3.



Brightness Control

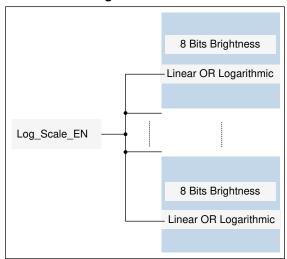


Figure 8-2. Logarithmic- or Linear-Scale Intensity Control

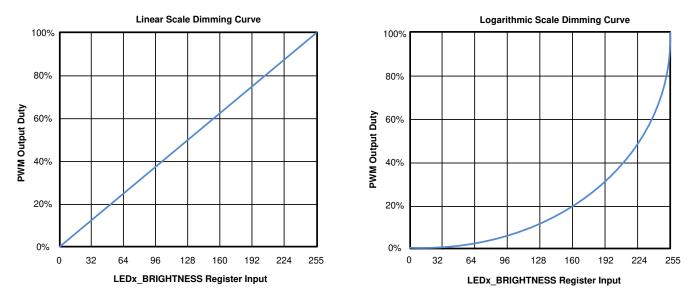


Figure 8-3. Logarithmic vs Linear Dimming Curve

8.3.1.3 12-Bit, 29-kHz PWM Generator Per Channel

8.3.1.3.1 PWM Generator

With the inputs of the color mixing and the intensity control, the final output PWM duty cycle is defined as the product obtained by multiplying the color-mixing register value by the related intensity-control register value. The final output PWM duty cycle has 12 bits of control accuracy, which is achieved by a 9 bits of pure PWM resolution and 3 bits of digital dithering control. For 3-bit dithering, every eighth pulse is made 1 LSB longer to increase the average value by 1 / 8th. The LP50xx device allows users to enable or disable the dithering function through the PWM_Dithering_EN register. When enabled (default), the output PWM duty-cycle accuracy is 12 bits. When disabled, the output PWM duty-cycle accuracy is 9 bits.

To eliminate the audible noise due to the PWM switching, the LP50xx device sets the PWM switching frequency at 29 kHz, above the 20-kHz human hearing range.

8.3.1.4 PWM Phase-Shifting

A PWM phase-shifting scheme allows delaying the time when each LED driver is active. When the LED drivers are not activated simultaneously, the peak load current from the pre-stage power supply is significantly

www.ti.com

decreased. The scheme also reduces input-current ripple and ceramic-capacitor audible ringing. LED drivers are grouped into three different phases.

- Phase 1—the rising edge of the PWM pulse is fixed. The falling edge of the pulse is changed when the duty cycle changes. Phase 1 is applied to LED0, LED3, LED6, LED9.
- Phase 2—the middle point of the PWM pulse is fixed. The pulse spreads in both directions when the PWM duty cycle is increased. Phase 2 is applied to LED1, LED4, LED7, LED10.
- Phase 3—the falling edge of the PWM pulse is fixed. The rising edge of the pulse is changed when the duty cycle changes. Phase 3 is applied to LED2, LED5, LED8, LED11.

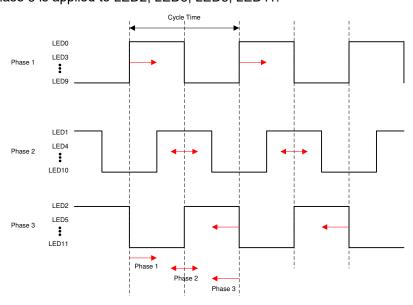


Figure 8-4. PWM Phase-Shifting

8.3.2 LED Bank Control

For most LED-animation effects, like blinking and breathing, all the RGB LEDs have the same lighting pattern. Instead of controlling the individual LED separately, which occupies the microcontroller resources heavily, the LP50xx device provides an easy coding approach, the LED bank control.

Each channel can be configured as either independent control or bank control through the LEDx_Bank_EN register. When LEDx Bank EN = 0 (default), the LED is controlled independently by the related color-mixing and intensity-control registers. When LEDx Bank EN = 1, the LP50xx device drives the LEDs in LED bank-control mode. The LED bank has its own independent PWM control scheme, which is the same structure as the PWM scheme of each channel. See *PWM Control for Each Channel* for more details. When a channel is configured in LED bank-control mode, the related color mixing and intensity control is governed by the bank control registers (BANK_A_COLOR, BANK_B_COLOR, BANK_C_COLOR, and BANK_BRIGHTNESS) regardless of the inputs on its own color-mixing and intensity-control registers.

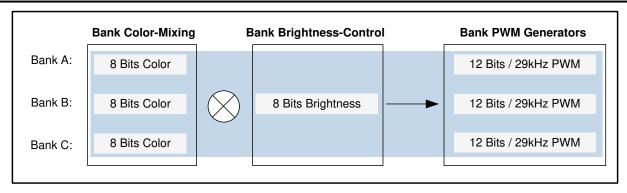


Figure 8-5. Bank PWM Control Scheme

Table 8-1. Bank Number and LED Number Assignment

OUT NUMBER	BANK NUMBER	RGB LED MODULE NUMBER
OUT0	Bank A	
OUT1	Bank B	LED0
OUT2	Bank C	
OUT3	Bank A	
OUT4	Bank B	LED1
OUT5	Bank C	
OUT6	Bank A	
OUT7	Bank B	LED2
OUT8	Bank C	
OUT9 (LP5012 only)	Bank A	
OUT10 (LP5012 only)	Bank B	LED3
OUT11 (LP5012 only)	Bank C	

With the bank control configuration, the LP50xx device enables users to achieve smooth and live LED effects globally with an ultrasimple software effort. Figure 8-6 shows an example using LED0 as an independent RGB indicator and others with group breathing effect.

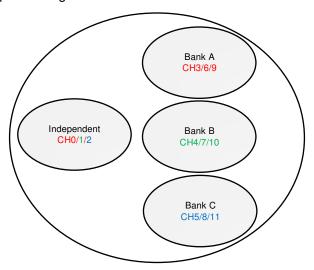


Figure 8-6. Bank PWM Control Example

8.3.3 Current Range Setting

The constant-current value (I_{SET}) of all 12 channels is set by a single external resistor, R_{IREF} . The value of R_{IREF} can be calculated by Equation 1.

$$R_{IREF} = K_{IREF} \times \frac{V_{IREF}}{I_{SET}}$$
 (1)

where:

- K_{IRFF} = 105
- V_{IRFF} = 0.7 V

With the IREF pin floating, the output current is close to zero. With the IREF pin shorted to GND, the LP50xx device provides internal current-limit protection, and the output-channel maximum current is limited to I_{LIM} .

The LP50xx device supports two levels of maximum output current, I_{MAX}.

- When V_{CC} is in the range from 2.7 V to 5.5 V, and the Max_Current_Option (bit) = 0, I_{MAX} = 25.5 mA.
- When V_{CC} is in the range from 3.3 V to 5.5 V, and the Max_Current_Option (bit) = 1, I_{MAX} = 35 mA.

8.3.4 Automatic Power-Save Mode

When all the LED outputs are inactive, the LP50xx device is able to enter power-save mode automatically, thus lowering idle-current consumption down to 10 μ A (typical). Automatic power-save mode is enabled when register bit Power_Save_EN = 1 (default) and all the LEDs are off for a duration of > 30 ms. Almost all analog blocks are powered down in power-save mode. If any I²C command to the device occurs, the LP50xx device returns to NORMAL mode.

8.3.5 Protection Features

8.3.5.1 Thermal Shutdown

The LP50xx device implements a thermal shutdown mechanism to protect the device from damage due to overheating. When the junction temperature rises to 160°C (typical), the device switches into shutdown mode. The LP50xx device releases thermal shutdown when the junction temperature of the device is reduced to 145°C (typical).

8.3.5.2 UVLO

The LP50xx device has an internal comparator that monitors the voltage at V_{CC} . When V_{CC} is below V_{UVF} , reset is active and the LP50xx device is in the INITIALIZATION state.

8.4 Device Functional Modes

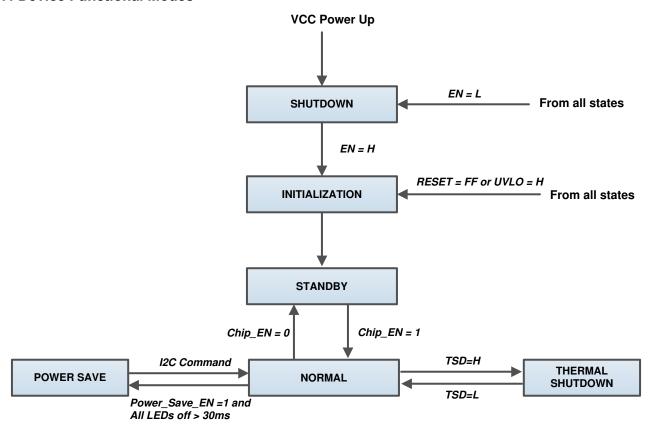


Figure 8-7. Functional Modes

- **INITIALIZATION**: The device enters into INITIALIZATION mode when EN = H. In this mode, all the registers are reset. Entry can also be from any state, if the RESET (register) = FFh or UVLO is active.
- NORMAL: The device enters the NORMAL mode when Chip_EN (register) = 1. I_{CC} is 10 mA (typical).
- **POWER SAVE**: The device automatically enters the POWER SAVE mode when Power_Save_EN (register) = 1 and all the LEDs are off for a duration of > 30 ms. In POWER SAVE mode, analog blocks are disabled to minimize power consumption, but the registers retain the data and keep it available via I²C. I_{CC} is 10 μA (typical). In case of any I²C command to this device, it returns to the NORMAL mode.
- SHUTDOWN: The device enters into SHUTDOWN mode from all states on V_{CC} power up or when EN = L.
 I_{CC} is < 1 μA (maximum).
- **STANDBY**: The device enters the STANDBY mode when Chip_EN (register) = 0. In this mode, all the OUTx pins are shut down, but the registers retain the data and keep it available via I²C. STANDBY is the low-power-consumption mode, when all circuit functions are disabled. I_{CC} is 10 μA (typical).
- THERMAL SHUTDOWN: The device automatically enters the THERMAL SHUTDOWN mode when the junction temperature exceeds 160°C (typical). In this mode, all the OUTx outputs are shut down. If the junction temperature decreases below 145°C (typical), the device returns to the NORMAL mode.

8.5 Programming

8.5.1 I²C Interface

The I²C-compatible two-wire serial interface provides access to the programmable functions and registers on the device. This protocol uses a two-wire interface for bidirectional communications between the devices connected to the bus. The two interface lines are the serial data line (SDA) and the serial clock line (SCL). Every device on the bus is assigned a unique address and acts as either a master or a slave depending on whether it generates or receives the serial clock, SCL. The SCL and SDA lines must each have a pullup resistor placed somewhere on the line and remain HIGH even when the bus is idle.

8.5.1.1 Data Validity

The data on SDA line must be stable during the HIGH period of the clock signal (SCL). In other words, the state of the data line can only be changed when the clock signal is LOW.

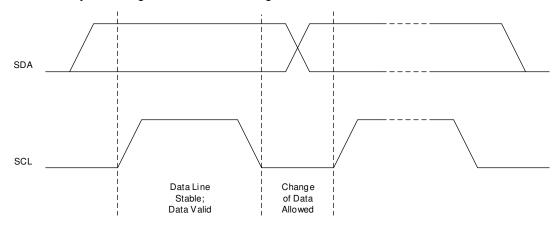


Figure 8-8. Data Validity

8.5.1.2 Start and Stop Conditions

START and STOP conditions classify the beginning and the end of the data transfer session. A START condition is defined as the SDA signal transitioning from HIGH to LOW while the SCL line is HIGH. A STOP condition is defined as the SDA transitioning from LOW to HIGH while SCL is HIGH. The bus master always generates START and STOP conditions. The bus is considered to be busy after a START condition and free after a STOP condition. During data transmission, the bus master can generate repeated START conditions. First START and repeated START conditions are functionally equivalent.

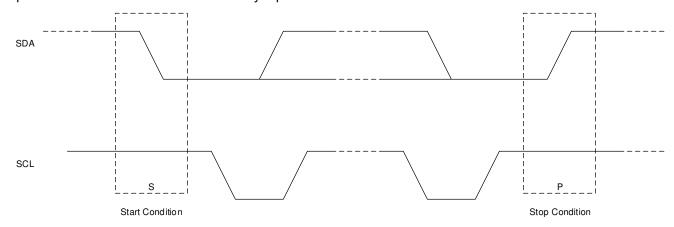


Figure 8-9. Start and Stop Conditions

8.5.1.3 Transferring Data

Every byte put on the SDA line must be eight bits long, with the most-significant bit (MSB) being transferred first. Each byte of data must be followed by an acknowledge bit. The acknowledge-related clock pulse is generated by the master. The master releases the SDA line (HIGH) during the acknowledge clock pulse. The device pulls down the SDA line during the ninth clock pulse, signifying an acknowledge. The device generates an acknowledge after each byte has been received.

There is one exception to the acknowledge-after-every-byte rule. When the master is the receiver, it must indicate to the transmitter an end of data by not acknowledging (negative acknowledge) the last byte clocked out of the slave. This negative acknowledge still includes the acknowledge clock pulse (generated by the master), but the SDA line is not pulled down.

After the START condition, the bus master sends a chip address. This address is seven bits long followed by an eighth bit which is a data direction bit (READ or WRITE). For the eighth bit, a 0 indicates a WRITE, and a 1 indicates a READ. The second byte selects the register to which the data is written. The third byte contains data to write to the selected register.

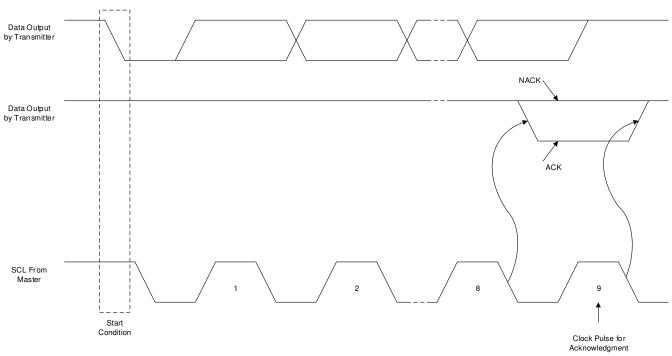


Figure 8-10. Acknowledge and Not Acknowledge on I²C Bus

8.5.1.4 I²C Slave Addressing

The device slave address is defined by connecting GND or VCC to the ADDR0 and ADDR1 pins. A total of four independent slave addresses can be realized by combinations when GND or VCC is connected to the ADDR0 and ADDR1 pins (see Table 8-2 and Table 8-3).

The device responds to a broadcast slave address regardless of the setting of the ADDR0 and ADDR1 pins. Global writes to the broadcast address can be used for configuring all devices simultaneously. The device supports global read using a broadcast address; however, the data read is only valid if all devices on the I²C bus contain the same value in the addressed register.

Table 8-2. Slave-Address Combinations

ADDR1	ADDRO	SLAVE ADDRESS			
ADDRI	ADDR0	INDEPENDENT	BROADCAST		
GND	GND	0010100			
GND	VCC	0010101	0001100		
VCC	GND	0010110	0001100		
VCC	VCC	0010111			

Table 8-3. Chip Address

		SLAVE ADDRESS						
	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Independent	0	0	1	0	1	ADDR1	ADDR0	1 or 0
Broadcast	0	0	0	1	1	0	0	1 or 0

8.5.1.5 Control-Register Write Cycle

- · The master device generates a start condition.
- The master device sends the slave address (7 bits) and the data direction bit (R/ \overline{W} = 0).
- · The slave device sends an acknowledge signal if the slave address is correct.
- The master device sends the control register address (8 bits).
- · The slave device sends an acknowledge signal.
- The master device sends the data byte to be written to the addressed register.
- · The slave device sends an acknowledge signal.
- If the master device sends further data bytes, the control register address of the slave is incremented by 1 after the acknowledge signal. To reduce program load time, the device supports address auto incrementation. The register address is incremented after each 8 data bits.
- The write cycle ends when the master device creates a stop condition.



Figure 8-11. Write Cycle

8.5.1.6 Control-Register Read Cycle

- The master device generates a start condition.
- The master device sends the slave address (7 bits) and the data direction bit (R/ \overline{W} = 0).
- The slave device sends an acknowledge signal if the slave address is correct.
- The master device sends the control register address (8 bits).
- The slave device sends an acknowledge signal.
- The master device generates a repeated-start condition.
- The master device sends the slave address (7 bits) and the data direction bit (R/ \overline{W} = 1).
- The slave device sends an acknowledge signal if the slave address is correct.
- · The slave device sends the data byte from the addressed register.
- If the master device sends an acknowledge signal, the control-register address is incremented by 1. The slave device sends the data byte from the addressed register. To reduce program load time, the device supports address auto incrementation. The register address is incremented after each 8 data bits.
- The read cycle ends when the master device does not generate an acknowledge signal after a data byte and generates a stop condition.

Copyright © 2020 Texas Instruments Incorporated



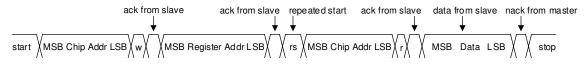


Figure 8-12. Read Cycle

8.5.1.7 Auto-Increment Feature

The auto-increment feature allows writing or reading several consecutive registers within one transmission. For example, when an 8-bit word is sent to the device, the internal address index counter is incremented by 1, and the next register is written. The auto-increment feature is enabled by default and can be disabled by setting the Auto_Incr_EN bit = 0 in the DEVICE_CONFIG1 register. The auto-increment feature is applied for the full register address from 0h to FFh.



8.6 Register Maps

Table 8-4 lists the memory-mapped registers of the device.

Table 8-4. Register Maps

REGISTER NAME	ADDR	TYPE	D7	D6	D5	D4	D3	D2	D1	D0	DEF- AULT
DEVICE_ CONFIG0	00h	R/W	RESERVED	Chip_EN		RESERVED				00h	
DEVICE_ CONFIG1	01h	R/W	RESE	RVED	Log_Scale_EN	Power_Save_ EN	Auto_Incr_EN	PWM_ Dithering_EN	Max_Current_ Option	LED_Global Off	3Ch
LED_CONFIG0	02h	R/W		RESERVED LED3_Bank_EN (Only for LP5012) LED2_Bank_EN LED1_Bank_EN LED0_Bank_EN						00h	
BANK_ BRIGHTNESS	03h	R/W				Bank_B	rightness				FFh
BANK_A_ COLOR	04h	R/W				Bank_/	A_Color				00h
BANK_B_ COLOR	05h	R/W				Bank_I	3_Color				00h
BANK_C_ COLOR	06h	R/W		Bank_C_Color 00							00h
LED0_ BRIGHTNESS	07h	R/W		LED0_Brightness FF							FFh
LED1_ BRIGHTNESS	08h	R/W				LED1_B	rightness				FFh
LED2_ BRIGHTNESS	09h	R/W				LED2_B	rightness				FFh
LED3_ BRIGHTNESS	0Ah	R/W					rightness · LP5012)				FFh
OUT0_COLOR	0Bh	R/W				OUT0	_Color				00h
OUT1_COLOR	0Ch	R/W				OUT1	_Color				00h
OUT2_COLOR	0Dh	R/W					_Color				00h
OUT3_COLOR	0Eh	R/W				OUT3	_Color				00h
OUT4_COLOR	0Fh	R/W				OUT4	_Color				00h
OUT5_COLOR	10h	R/W				OUT5	_Color				00h
OUT6_COLOR	11h	R/W				OUT6	_Color				00h
OUT7_COLOR	12h	R/W		OUT7_Color 00						00h	
OUT8_COLOR	13h	R/W		OUT8_Color 00						00h	

Copyright © 2020 Texas Instruments Incorporated



Table 8-4. Register Maps (continued)

REGISTER NAME	ADDR	TYPE	D7	D6	D5	D4	D3	D2	D1	D0	DEF- AULT
OUT9_COLOR	14h	R/W		OUT9_Color (Only for LP5012) 00h							
OUT10_COLOR	15h	R/W		OUT10_Color (Only for LP5012) 001							
OUT11_COLOR	16h	R/W		OUT11_Color (Only for LP5012)							00h
RESET	17h	W		Reset 00h							00h

Table 8-5. Access Type Codes

14515 5 517155555 1375 55455									
ACCESS TYPE CODE		DESCRIPTION							
Read Type									
R	R	Read							
Write Type									
W	W	Write							
Reset or Default	Value								
-n		Value after reset or the default value							

8.6.1 DEVICE_CONFIG0 (Address = 0h) [reset = 0h]

DEVICE_CONFIG0 is shown in Figure 8-13 and described in Table 8-6.

Return to Table 8-4.

Figure 8-13. DEVICE_CONFIG0 Register

					- 9			
7	6	5	4	3	2	1	0	
RESERVED	Chip_EN	RESERVED						
R/ W-0h	R/ W-0h	R/ W-0h						

Table 8-6. DEVICE_CONFIG0 Register Field Descriptions

				<u> </u>
Bit	Field	Туре	Reset	Description
7	RESERVED	R/W	0h	Reserved
6	Chip_EN	R/ W	0h	1 = LP50xx enabled 0 = LP50xx not enabled
5–0	RESERVED	R/W	0h	Reserved

8.6.2 DEVICE_CONFIG1 (Address = 1h) [reset = 3Ch]

DEVICE_CONFIG1 is shown in Figure 8-14 and described in Table 8-7.

Return to Table 8-4.

Figure 8-14. DEVICE CONFIG1 Register

7	6 5 4		4	3	2	1	0
RESE	ERVED	Log_Scale_EN	Power_Save_E N	Auto_Incr_EN	PWM_Dithering _EN	Optional_Headr oom	LED_Global Off
R/ \(\bar{\gamma}\)	W-0h	R/ W-1h	R/ W-1h	R/ W-1h	R/ W-1h	R/ W-0h	R/ W-0h

Table 8-7. DEVICE_CONFIG1 Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–6	RESERVED	R/W	0h	Reserved
5	Log_Scale_EN	R/W	1h	1 = Logarithmic scale dimming curve enabled 0 = Linear scale dimming curve enabled
4	Power_Save_EN	R/W	1h	1 = Automatic power-saving mode enabled 0 = Automatic power-saving mode not enabled
3	Auto_Incr_EN	R/W	1h	1 = Automatic increment mode enabled 0 = Automatic increment mode not enabled
2	PWM_Dithering_EN	R/W	1h	1 = PWM dithering mode enabled 0 = PWM dithering mode not enabled
1	Max_Current_Option	R/W	0h	1 = Output maximum current I _{MAX} = 35 mA. 0 = Output maximum current I _{MAX} = 25.5 mA.
0	LED_Global Off	R/W	0h	1 = Shut down all LEDs 0 = Normal operation

8.6.3 LED_CONFIG0 (Address = 2h) [reset = 00h]

LED_CONFIG0 is shown in Figure 8-15 and described in Table 8-8.

Return to Table 8-4.

Figure 8-15. LED_CONFIG0 Register



Table 8-8. LED_CONFIG0 Register Field Descriptions

Bit	Field	d Type Reset I		Description
7-4	RESERVED	R/W	0h	Reserved
3	LED3_Bank_EN	R/ W	0h	1 = LED3 bank control mode enabled 0 = LED3 Independent control mode enabled
2	LED2_Bank_EN	R/ W	0h	1 = LED2 bank control mode enabled 0 = LED2 independent control mode enabled
1	LED1_Bank_EN	R/W	0h	1 = LED1 bank control mode enabled 0 = LED1 independent control mode enabled
0	LED0_Bank_EN	R/W	0h	1 = LED0 bank control mode enabled 0 = LED0 independent control mode enabled

8.6.4 BANK_BRIGHTNESS (Address = 3h) [reset = FFh]

BANK BRIGHTNESS is shown in Figure 8-16 and described in Table 8-9.

Return to Table 8-4.

Figure 8-16. BANK_BRIGHTNESS Register



Table 8-9. BANK_BRIGHTNESS Register Field Descriptions

Bit	Field	Туре	Reset	Description
				FFh = 100% of full brightness
7–0	Bank_Brightness	R/ W	FFh	 80h = 50% of full brightness
				 00h = 0% of full brightness

8.6.5 BANK_A_COLOR (Address = 4h) [reset = 00h]

BANK_A_COLOR is shown in Figure 8-17 and described in Table 8-10.

Return to Table 8-4.

Figure 8-17. BANK A COLOR Register

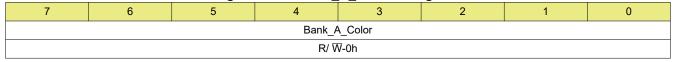




Table 8-10. BANK_A_COLOR Register Field Descriptions

				5
Bit	Field	Туре	Reset	Description
				FFh = The color mixing percentage is 100%.
7–0	Bank_A_Color	R/ W	0h	 80h = The color mixing percentage is 50%.
				00h = The color mixing percentage is 0%.



8.6.6 BANK_B_COLOR (Address = 5h) [reset = 00h]

BANK B COLOR is shown in Figure 8-18 and described in Table 8-11.

Return to Table 8-4.

Figure 8-18. BANK_B_COLOR Register

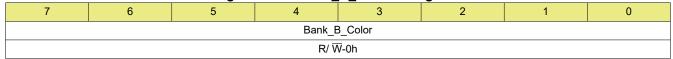


Table 8-11. BANK_B_COLOR Register Field Descriptions

				<u> </u>
Bit	Field	Туре	Reset	Description
7–0	Bank_B_Color	R/ ₩		FFh = The color mixing percentage is 100% 80h = The color mixing percentage is 50%.
				 00h = The color mixing percentage is 0%.

8.6.7 BANK_C_COLOR (Address = 6h) [reset = 00h]

BANK_C_COLOR is shown in Figure 8-19 and described in Table 8-12.

Return to Table 8-4.

Figure 8-19. BANK_C_COLOR Register

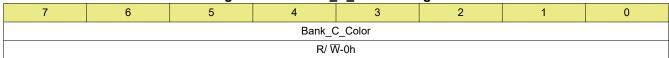


Table 8-12. BANK C COLOR Register Field Descriptions

				•
Bit	Field	Туре	Reset	Description
				FFh = The color mixing percentage is 100%.
7–0	Bank_C_Color	R/W	0h	 80h = The color mixing percentage is 50%.
				00h = The color mixing percentage is 0%.

8.6.8 LED0_BRIGHTNESS (Address = 7h) [reset = FFh]

LED0 BRIGHTNESS is shown in Figure 8-20 and described in Table 8-13.

Return to Table 8-4.

Figure 8-20. LED0_BRIGHTNESS Register

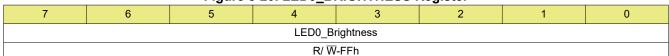


Table 8-13. LED0_BRIGHTNESS Register Field Descriptions

Bit	Field	Туре	Reset	Description
				FFh = 100% of full intensity
7–0	LED0_Brightness	R/ W	FFh	 80h = 50% of full intensity
				 00h = 0% of full intensity

8.6.9 LED1_BRIGHTNESS (Address = 8h) [reset = FFh]

LED1_BRIGHTNESS is shown in Figure 8-21 and described in Table 8-14.

Return to Table 8-4.

Figure 8-21. LED1_BRIGHTNESS Register

7	6	5	4	3 2		1	0		
LED1_Brightness									
R/ W̄-FFh									

Table 8-14. LED1_BRIGHTNESS Register Field Descriptions

ield	Туре	Reset	Description
			FFh = 100% of full intensity
ED1_Brightness	R/W		80h = 50% of full intensity 00h = 0% of full intensity
		_	D1_Brightness R/ W FFh

8.6.10 LED2_BRIGHTNESS (Address = 9h) [reset = FFh]

LED2_BRIGHTNESS is shown in Figure 8-22 and described in Table 8-15.

Return to Table 8-4.

Figure 8-22. LED2_BRIGHTNESS Register

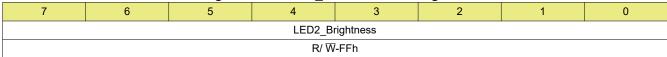


Table 8-15. LED2_BRIGHTNESS Register Field Descriptions

Bit	Field	Туре	Reset	Description
				FFh = 100% of full intensity
7–0	LED2_Brightness	R/W	FFh	 80h = 50% of full intensity
				00h = 0% of full intensity

8.6.11 LED3_BRIGHTNESS (Address = 0Ah) [reset = FFh]

LED3_BRIGHTNESS is shown in Figure 8-23 and described in Table 8-16.

Return to Table 8-4.

Figure 8-23. LED3_BRIGHTNESS Register

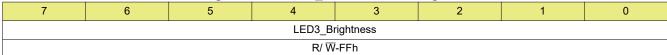


Table 8-16. LED3_BRIGHTNESS Register Field Descriptions

Bit	Field	Туре	Reset	Description
				FFh = 100% of full intensity
7–0	LED3_Brightness	R/W		80h = 50% of full intensity 00h = 0% of full intensity



8.6.12 OUT0_COLOR (Address = 0Bh) [reset = 00h]

OUT0_COLOR is shown in Figure 8-24 and described in Table 8-17.

Return to Table 8-4.

Figure 8-24. OUT0_COLOR Register

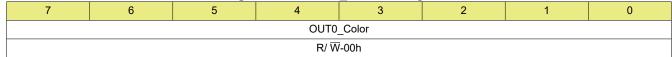


Table 8-17. OUT0_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
				FFh = The color mixing percentage is 0%.
7–0	OUT0_Color	R/W	00h	 80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

8.6.13 OUT1_COLOR (Address = 0Ch) [reset = 00h]

OUT1_COLOR is shown in Figure 8-25 and described in Table 8-18.

Return to Table 8-4.

Figure 8-25. OUT1_COLOR Register

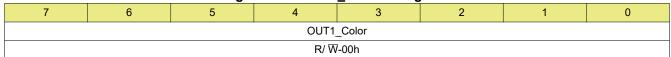


Table 8-18. OUT1 COLOR Register Field Descriptions

				•
Bit	Field	Туре	Reset	Description
				FFh = The color mixing percentage is 0%.
7–0	OUT1_Color	R/W	00h	 80h =The color mixing percentage is 50%.
				 00h = The color mixing percentage is 100%.

8.6.14 OUT2_COLOR (Address = 0Dh) [reset = 00h]

OUT2 COLOR is shown in Figure 8-26 and described in Table 8-19.

Return to Table 8-4.

Figure 8-26. OUT2_COLOR Register

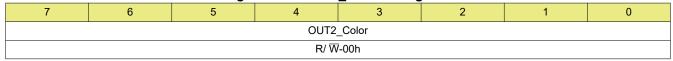


Table 8-19. OUT2_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
				FFh = The color mixing percentage is 0%.
7–0	OUT2_Color	R/ W	00h	80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

8.6.15 OUT3_COLOR (Address = 0Eh) [reset = 00h]

OUT3_COLOR is shown in Figure 8-27 and described in Table 8-20.

Return to Table 8-4.

Figure 8-27. OUT3_COLOR Register

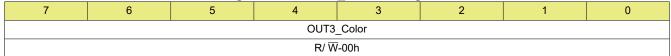


Table 8-20. OUT3_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	OUT3_Color	R/ W	00h	FFh = The color mixing percentage is 0% 80h =The color mixing percentage is 50% 00h = The color mixing percentage is 100%.

8.6.16 OUT4_COLOR (Address = 0Fh) [reset = 00h]

OUT4_COLOR is shown in Figure 8-28 and described in Table 8-21.

Return to Table 8-4.

Figure 8-28. OUT4_COLOR Register

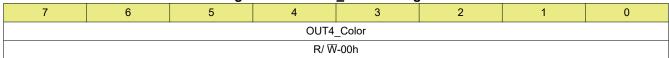


Table 8-21. OUT4_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
				FFh = The color mixing percentage is 0%.
7–0	OUT4_Color	R/W	00h	 80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

8.6.17 OUT5_COLOR (Address = 10h) [reset = 00h]

OUT5_COLOR is shown in Figure 8-29 and described in Table 8-22.

Return to Table 8-4.

Figure 8-29. OUT5_COLOR Register

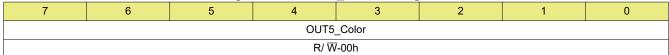


Table 8-22. OUT5_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
				FFh = The color mixing percentage is 0%.
7–0	OUT5_Color	R/W		80h =The color mixing percentage is 50% 00h = The color mixing percentage is 100%.



8.6.18 OUT6_COLOR (Address = 11h) [reset = 00h]

OUT6_COLOR is shown in Figure 8-30 and described in Table 8-23.

Return to Table 8-4.

Figure 8-30. OUT6_COLOR Register

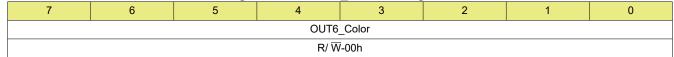


Table 8-23. OUT6_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
				FFh = The color mixing percentage is 0%.
7–0	OUT6_Color	R/ W	00h	80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

8.6.19 OUT7 COLOR (Address = 12h) [reset = 00h]

OUT7_COLOR is shown in Figure 8-31 and described in Table 8-24.

Return to Table 8-4.

Figure 8-31. OUT7_COLOR Register

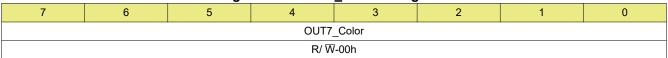


Table 8-24. OUT7 COLOR Register Field Descriptions

				•
Bit	Field	Туре	Reset	Description
				FFh = The color mixing percentage is 0%.
7–0	OUT7_Color	R/W	00h	 80h =The color mixing percentage is 50%.
				 00h = The color mixing percentage is 100%.

8.6.20 OUT8_COLOR (Address = 13h) [reset = 00h]

OUT8 COLOR is shown in Figure 8-32 and described in Table 8-25.

Return to Table 8-4.

Figure 8-32. OUT8_COLOR Register

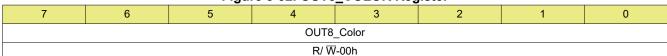


Table 8-25. OUT8_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
				FFh = The color mixing percentage is 0%.
7–0	OUT8_Color	R/W	00h	80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

8.6.21 OUT9_COLOR (Address = 14h) [reset = 00h]

OUT9_COLOR is shown in Figure 8-33 and described in Table 8-26.



Return to Table 8-4.

Figure 8-33. OUT9_COLOR Register

7	6	5	4	3	2	1	0		
OUT9_Color									
	R/ W-00h								

Table 8-26. OUT9_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
				FFh = The color mixing percentage is 0%.
7–0	OUT9_Color	R/W	00h	80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

8.6.22 OUT10_COLOR (Address = 15h) [reset = 00h]

OUT10_COLOR is shown in Figure 8-34 and described in Table 8-27.

Return to Table 8-4.

Figure 8-34. OUT10_COLOR Register

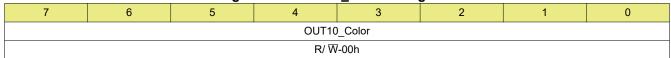


Table 8-27. OUT10_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
				FFh = The color mixing percentage is 0%.
7–0	OUT10_Color	R/W	00h	80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

8.6.23 OUT11_COLOR (Address = 16h) [reset = 00h]

OUT11 COLOR is shown in Figure 8-35 and described in Table 8-28.

Return to Table 8-4.

Figure 8-35. OUT11_COLOR Register

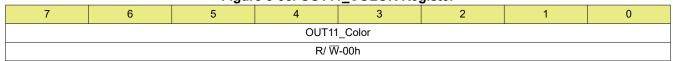


Table 8-28. OUT11_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
				FFh = The color mixing percentage is 0%.
7–0	OUT11_Color	R/W	00h	80h =The color mixing percentage is 50%.
				00h = The color mixing percentage is 100%.

8.6.24 RESET (Address = 17h) [reset = 00h]

RESET is shown in Figure 8-36 and described in Table 8-29.

Return to Table 8-4.

Figure 8-36. RESET Register



Product Folder Links: LP5009 LP5012



Figure 8-36. RESET Register (continued)

, , , , , , , , , , , , , , , , , , , ,
Reset
W-00h

Table 8-29. OUT14_COLOR Register Field Descriptions

Bit	Field	Туре	Reset	Description
7–0	Reset	W	00h	FFh = Reset all the registers to default value.

Submit Document Feedback

Product Folder Links: LP5009 LP5012



9 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The LP50xx device is a 9- or 12-channel constant-current-sink LED driver. The LP50xx device improves the user experience in color mixing and intensity control, for both live effects and coding effort. The optimized performance for RGB LEDs makes it a good choice for human-machine interaction applications.

9.2 Typical Application

The LP50xx design supports up to four devices in parallel with different configurations on the ADDR0 and ADDR1 pins.

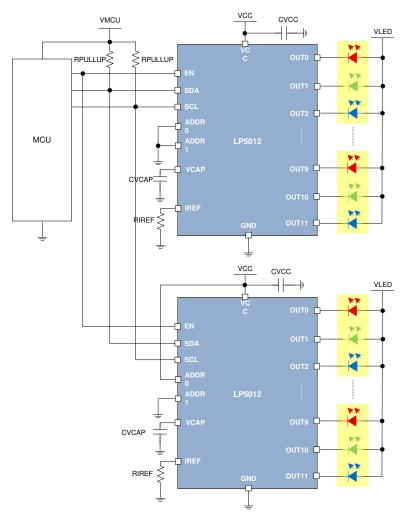


Figure 9-1. Driving Dual LP5012 Application Example

9.2.1 Design Requirements

Set the LED current to 15 mA using the R_{IREF} resistor. Select the proper value for the other external components, like VCAP pin capacitor and the SCL/SDA pullup resisters.

9.2.2 Detailed Design Procedure

LP50xx scales up the reference current (I_{REF}) set by the external resistor (R_{IREF}) to sink the output current (I_{OUT}) at each output port. The following formula can be used to calculate the external resistor (R_{IREF}):

$$R_{IREF} = K_{IREF} \times \frac{V_{IREF}}{I_{SET}}$$
 (2)

The SCL and SDA lines must each have a pullup resistor placed somewhere on the line (the pullup resistors are normally located on the bus master). In typical applications, values of 1.8 k Ω to 4.7 k Ω are used.

VCAP is internal LDO output pin. This pin must be connected through a 1-µF capacitor to GND. Place the capacitor as close to the device as possible.

TI recommends having a 1-µF capacitor between VCC and GND to ensure proper operation. Place the capacitor as close to the device as possible.

9.2.3 Application Curves

The test condition for Figure 9-2 is that the testing under bank control, with the register's (0x04, 0x05, 0x06) value is 0xF0.

The test condition for Figure 9-3 is that the testing under bank control, with the register's (0x04, 0x05, 0x06) value is 0x0F.

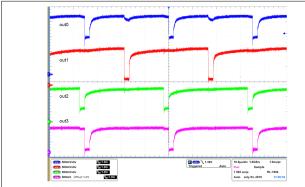


Figure 9-2. Current Waveform of OUT0, OUT1, OUT2 and OUT3

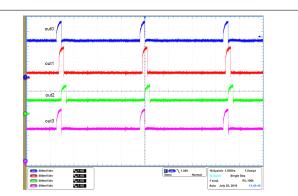


Figure 9-3. Current Waveform of OUT0, OUT1, OUT2 and OUT3



10 Power Supply Recommendations

The device is designed to operate from a V_{VCC} input-voltage supply range from 2.7 V and 5.5 V. This input supply must be well-regulated and able to withstand maximum input current and maintain stable voltage without voltage drop even in a load-transition condition (start-up or rapid intensity change). The resistance of the input supply rail must be low enough that the input-current transient does not cause a drop below a 2.7-V level in the LP50xx V_{VCC} supply voltage.

11 Layout

11.1 Layout Guidelines

To prevent thermal shutdown, the junction temperature, T_J , must be less than $T_{(TSD)}$. If the voltage drop across the output channels is high, the device power dissipation can be large. The LP50xx device has very good thermal performance because of the thermal pad design; however, the PCB layout is also very important to ensure that the device has good thermal performance. Good PCB design can optimize heat transfer, which is essential for the long-term reliability of the device.

Use the following guidelines when designing the device layout:

- Place the C_{VCAP}, C_{VCC}and R_{IREF} as close to the device as possible. Also, TI recommends putting the ground plane as Figure 11-1 and Figure 11-2.
- Maximize the copper coverage on the PCB to increase the thermal conductivity of the board. The major heat flow path from the package to the ambient is through copper on the PCB. Maximum copper density is extremely important when no heat sinks are attached to the PCB on the other side from the package.
- Add as many thermal vias as possible directly under the package ground pad to optimize the thermal conductivity of the board.
- Use either plated-shut or plugged and capped vias for all the thermal vias on both sides of the board to prevent solder voids. To ensure reliability and performance, the solder coverage must be at least 85%.



11.2 Layout Examples

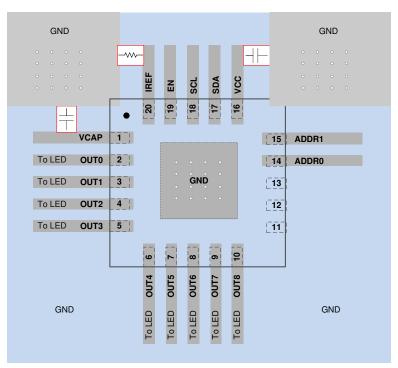


Figure 11-1. LP5009RUK Layout Example

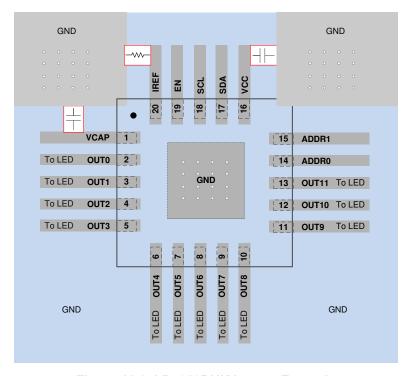


Figure 11-2. LP5012RUK Layout Example



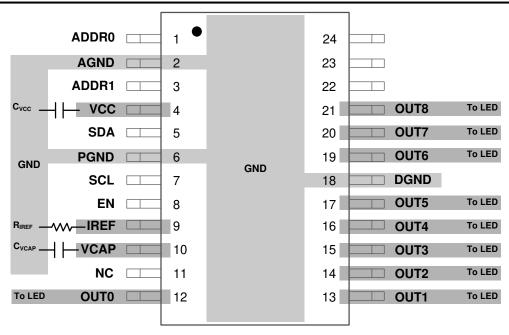


Figure 11-3. LP5009PW Layout Example

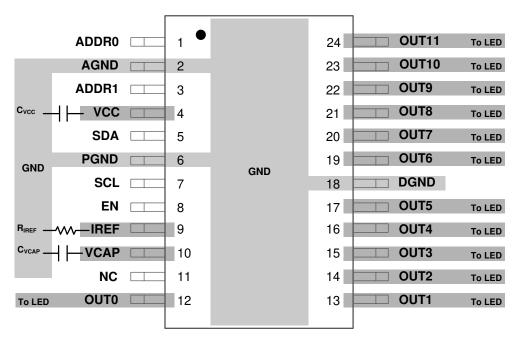


Figure 11-4. LP5012PW Layout Example

12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

Table 12-1. Related Links

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
LP5009	Click here	Click here	Click here	Click here	Click here
LP5012	Click here	Click here	Click here	Click here	Click here

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most-current data available for the designated devices. This data is subject to change without notice and without revision of this document. For browser-based versions of this data sheet, see the left-hand navigation pane.

Submit Document Feedback

Copyright © 2020 Texas Instruments Incorporated

www.ti.com 17-Jun-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
LP5009PWR	Active	Production	TSSOP (PW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LP5009PWR
LP5009PWR.A	Active	Production	TSSOP (PW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LP5009PWR
LP5009RUKR	Active	Production	WQFN (RUK) 20	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LP5009
LP5009RUKR.A	Active	Production	WQFN (RUK) 20	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LP5009
LP5009RUKRG4	Active	Production	WQFN (RUK) 20	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LP5009
LP5009RUKRG4.A	Active	Production	WQFN (RUK) 20	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LP5009
LP5012PWR	Active	Production	TSSOP (PW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LP5012PWR
LP5012PWR.A	Active	Production	TSSOP (PW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LP5012PWR
LP5012RUKR	Active	Production	WQFN (RUK) 20	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LP5012
LP5012RUKR.A	Active	Production	WQFN (RUK) 20	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LP5012

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

www.ti.com 17-Jun-2025

and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 9-Oct-2025

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LP5009PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
LP5009RUKR	WQFN	RUK	20	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LP5009RUKRG4	WQFN	RUK	20	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
LP5012PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
LP5012RUKR	WQFN	RUK	20	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2



www.ti.com 9-Oct-2025



*All dimensions are nominal

7 III GIII I GII I GI GI GI GI GI GI GI G							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LP5009PWR	TSSOP	PW	24	2000	353.0	353.0	32.0
LP5009RUKR	WQFN	RUK	20	3000	367.0	367.0	35.0
LP5009RUKRG4	WQFN	RUK	20	3000	367.0	367.0	35.0
LP5012PWR	TSSOP	PW	24	2000	353.0	353.0	32.0
LP5012RUKR	WQFN	RUK	20	3000	367.0	367.0	35.0



SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

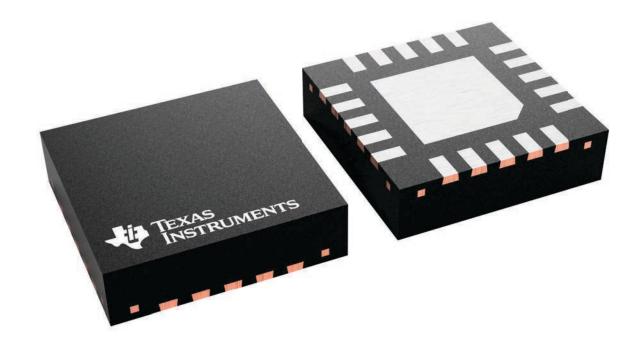
- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



3 x 3, 0.4 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

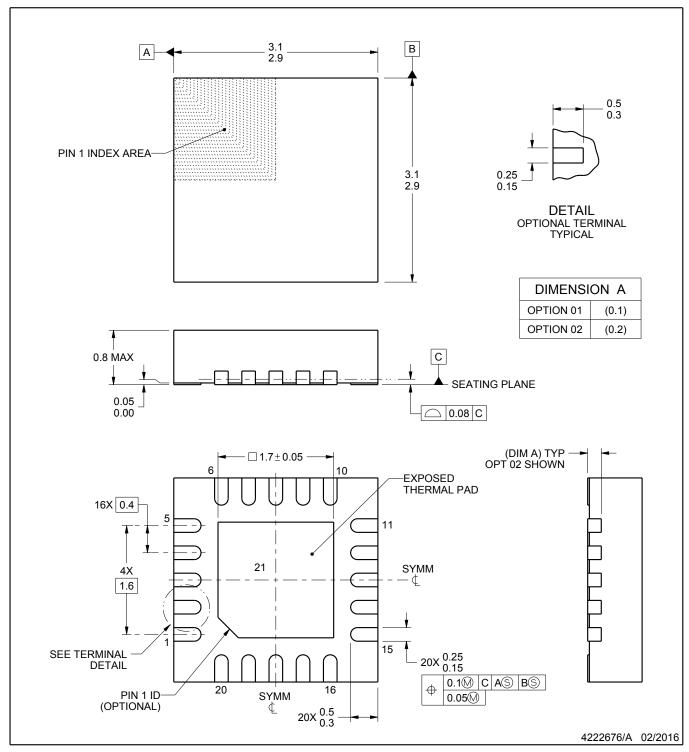
This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



INSTRUMENTS www.ti.com



PLASTIC QUAD FLATPACK - NO LEAD



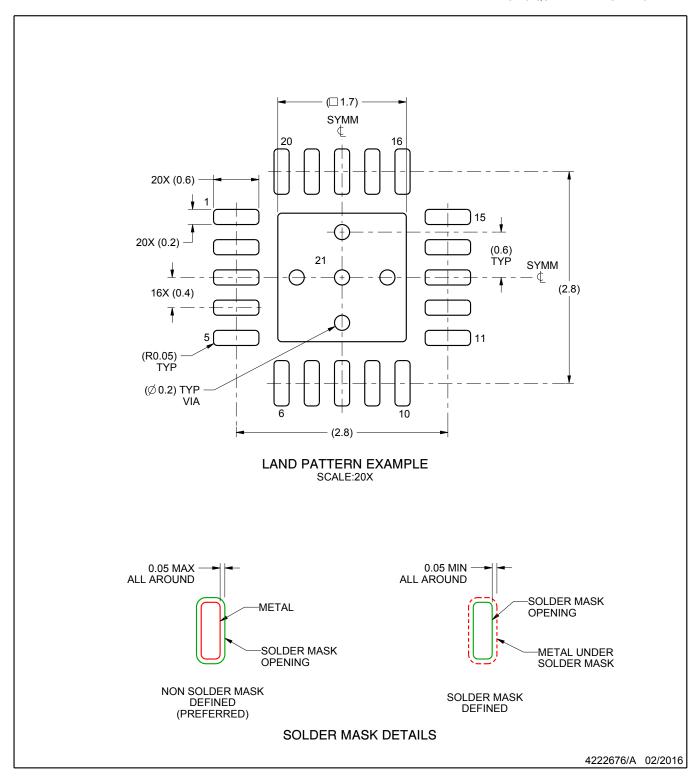
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

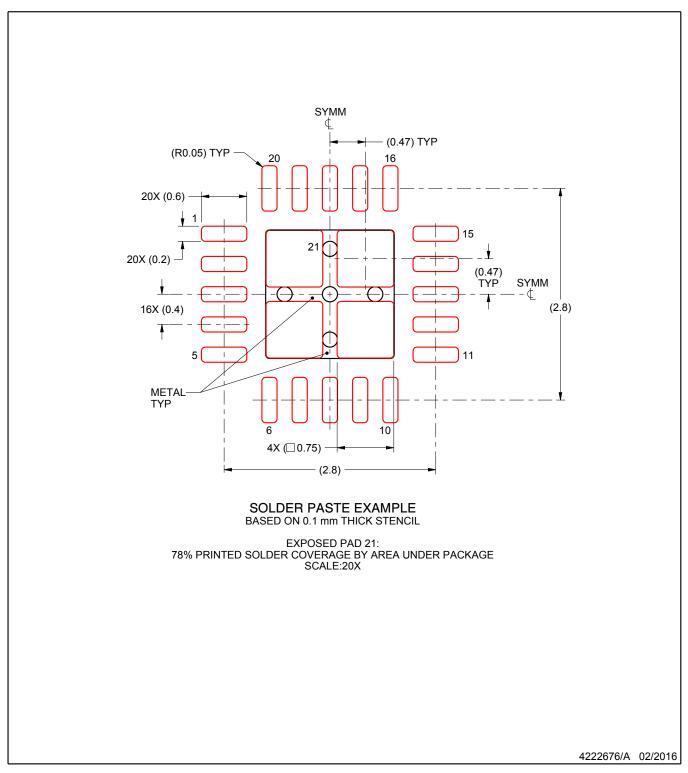


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025. Texas Instruments Incorporated